INTEGRATED CIRCUITS

DATA SHEET

74LVT273 3.3V Octal D flip-flop

Product specification
Supersedes data of 1994 May 11
IC23 Data Handbook







74LVT273

FEATURES

- Eight edge-triggered D-type flip-flops
- Buffered common clock
- Buffered asynchronous Master Reset
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Power-up reset
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Latchup protection exceeds 500 mA per JEDEC Std 17
- ESD protection exceeds 2000V per Mil Std 883 Method 3015 and 200V per Machine Model.

DESCRIPTION

The LVT273 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset (MR) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the Low-to-High clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced Low independent of Clock or Data inputs by a Low voltage level on the $\overline{\text{MR}}$ input. The device is useful for applications where the true output only is required and the CP and $\overline{\text{MR}}$ are common elements.

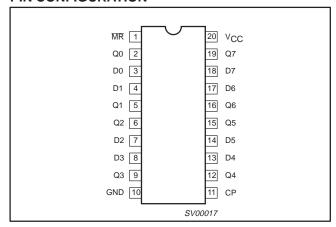
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay CP to Qn	$C_L = 50pF; V_{CC} = 3.3V$	3.5 3.5	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	4	pF

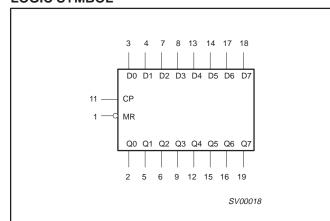
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SOL	-40°C to +85°C	74LVT273 D	74LVT273 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +85°C	74LVT273 DB	74LVT273 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVT273 PW	74LVT273PW DH	SOT360-1

PIN CONFIGURATION



LOGIC SYMBOL

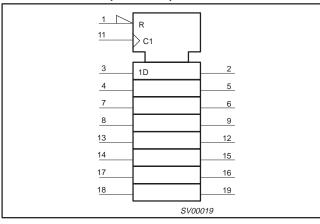


Philips Semiconductors Product specification

3.3V Octal D flip-flop

74LVT273

LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

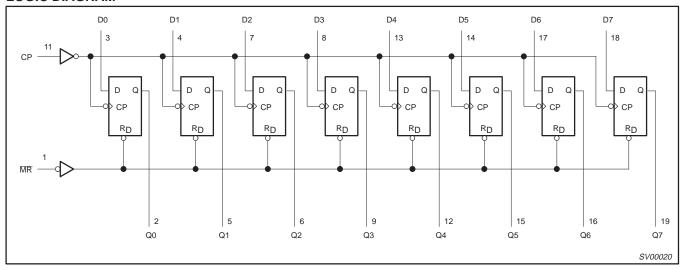
	INPUTS		OUTPUTS	OPERATING MODE		
MR	СР	D _n	Q0 – Q7			
L	Х	Х	L	Reset (clear)		
Н	↑	h	Н	Load "1"		
Н	1	Ι	L	Load "0"		
Н	L	Х	Q_0	Retain state		

- H = High voltage level
 h = High voltage level one set-up time prior to the Low-to-High clock transition
- Low voltage level
 Low voltage level one set-up time prior to the Low-to-High
- = Don't care
- $\uparrow = \text{Low-to-High clock transition}$ $Q_0 = \text{Output as it was}$

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
11	СР	Clock pulse input (active rising edge)
3, 4, 7, 8, 13, 14, 17, 18	D0 – D7	Data inputs
2, 5, 6, 9, 12, 15, 16, 19	Q0 – Q7	Data outputs
1	MR	Master Reset input (active-Low)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

LOGIC DIAGRAM



Philips Semiconductors Product specification

3.3V Octal D flip-flop

74LVT273

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
lok	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +7.0	V
	DC output ourrent	Output in Low state	128	A
Гоит	DC output current	Output in High State	-64	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWIBOL	PARAMETER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		64	mA
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

1998 Feb 19 4

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

^{3.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74LVT273

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	= -40°C to +	-85°C	UNIT
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-0.9	-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V _{CC} -0.2	V _{CC} -0.1		
V_{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -8mA		2.4	2.5		V
		V _{CC} = 3.0V; I _{OH} = -32mA		2.0	2.2		
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.1	0.2	
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	
V_{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA		0.25	0.4	V	
		V _{CC} = 3.0V; I _{OL} = 32mA		0.3	0.5		
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
V _{RST}	Power-up output low voltage ⁴	V_{CC} = 3.6V; I_{O} = 1mA; V_{I} = GND or V_{CC}		0.13	0.55	V	
		$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$		1	10		
	l	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		±0.1	±1] .
I _I	Input leakage current	$V_{CC} = 3.6V; V_{I} = V_{CC}$	Data nine3		0.1	1	μΑ
		V _{CC} = 3.6V; V _I = 0	Data pins ³		-1	-5	
I _{OFF}	Output off current	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			1	±100	μΑ
		$V_{CC} = 3V; V_I = 0.8V$		75	150		
I_{HOLD}	Bus Hold current A inputs ⁵	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-150		μΑ
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			60	125	μΑ
I _{CCH}	Outros and assemble assemble	$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or		0.13	0.19		
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or	V _{CC} , I _O = 0		3	12	mA
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6 Other inputs at V_{CC} or GND	SV,		0.1	0.2	mA

NOTES:

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
 Unused pins at V_{CC} or GND.
- 4. For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.
- 5. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$, $R_L = 500 \Omega$; $T_{amb} = -40 ^{\circ} \text{C}$ to $+85 ^{\circ} \text{C}$.

SYMBOL	PARAMETER	WAVEFORM	Vcc	c = 3.3V ±0	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
f _{MAX}	Maximum clock frequency	1	150				MHz
t _{PLH} t _{PHL}	Propagation delay CP to Qn	1	1.7 1.9	3.5 3.5	5.5 5.5	6.3 5.9	ns
t _{PHL}	Propagation delay MR to Qn	2	1.3	3.2	6.2	6.2	ns

5

^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC SETUP REQUIREMENTS

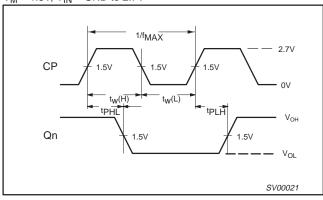
GND = 0V; $t_R = t_F = 2.5 ns$; $C_L = 50 pF$, $R_L = 50 0\Omega$, $T_{amb} = -40 ^{\circ} C$ to +85 $^{\circ} C$.

SYMBOL	PARAMETER	WAVEFORM	V _{CC} = +3	.3 ± 0.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP	MIN	
t _s (H) t _s (L)	Setup time, High or Low Dn to CP	3	2.3 2.3	1.0 1.0	2.7 2.7	ns
t _h (H) t _h (L)	Hold time, High or Low Dn to CP	3	0 0	-0.6 -0.6	0 0	ns
t _w (H) t _w (L)	Clock pulse width High or Low	1	3.3 3.3	1.5 1.5	3.3 3.3	ns
t _w (L)	Master Reset pulse width, Low	2	3.3	1.5	3.3	ns
t _{REC}	Recovery time MR to CP	2	2.7	1.0	3.2	ns

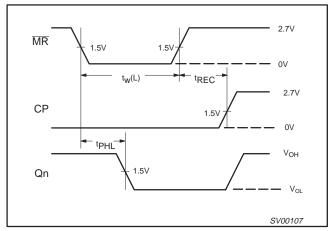
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AC WAVEFORMS

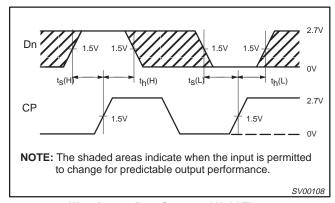
 V_M = 1.5V, V_{IN} = GND to 2.7V



Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



Waveform 2. Master Reset Pulse Width, Master Reset to Output Delay and Master Reset to Clock Recovery Time



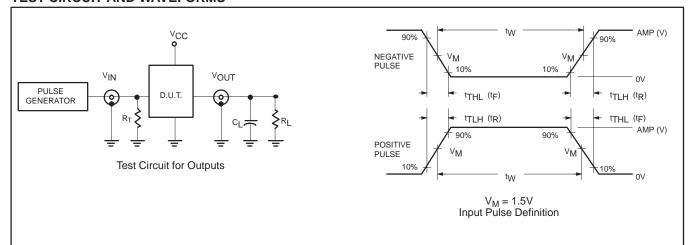
Waveform 3. Data Setup and Hold Times

Philips Semiconductors Product specification

3.3V Octal D flip-flop

74LVT273

TEST CIRCUIT AND WAVEFORMS



DEFINITIONS

 R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

FAMILY	INPUT PULSE REQUIREMENTS								
FAMILI	Amplitude	Rep. Rate	t _W	t _R	t _F				
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns				

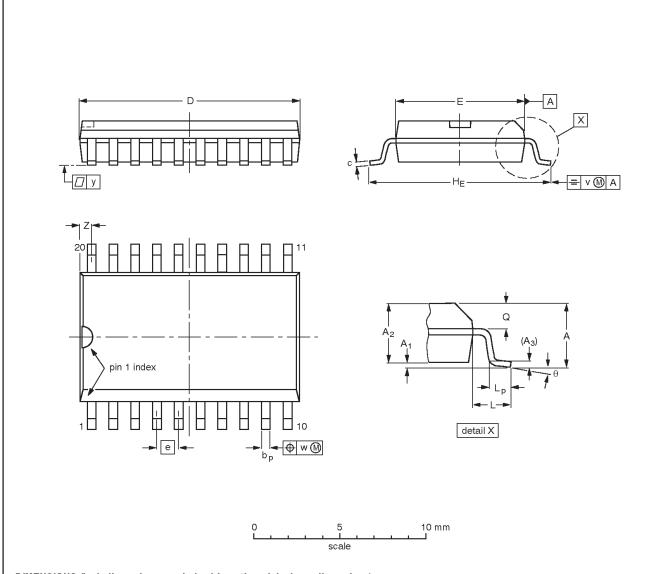
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1998 Feb 19 7

74LVT273

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

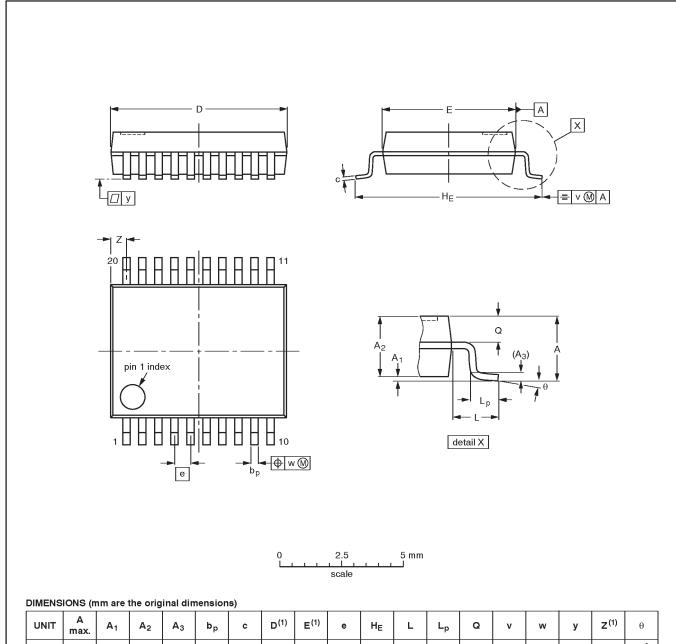
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEDEC EIAJ		PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013AC				-95-01-24 97-05-22	

8

74LVT273

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



UNIT	A max.	Α1	A ₂	А3	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

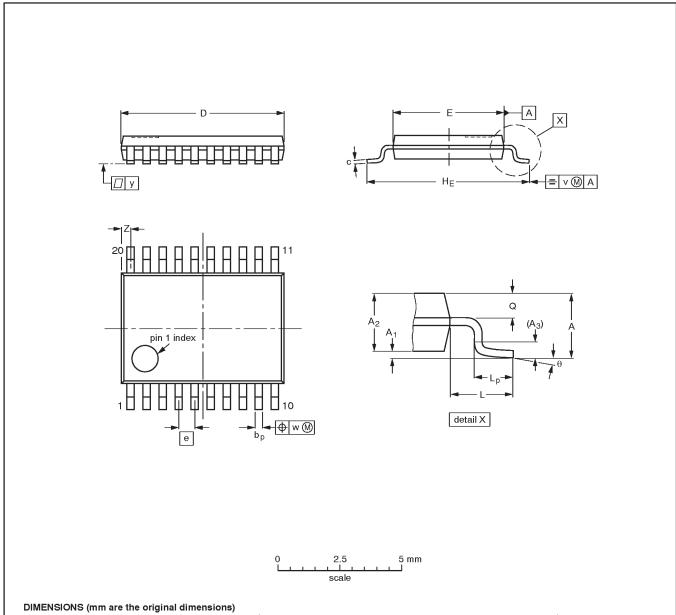
1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

Γ	OUTLINE		REFER	RENCES	EUROPEAN	ICCUE DATE
	VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
	SOT339-1		MO-150AE			93-09-08 95-02-04

74LVT273

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



						-,												
UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUEDATE
SOT360-1		MO-153AC			93-06-16 95-02-04

1998 Feb 19 10

Philips Semiconductors Product specification

3.3V Octal D flip-flop

74LVT273

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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